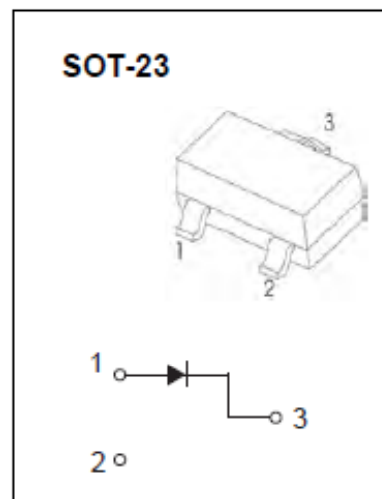
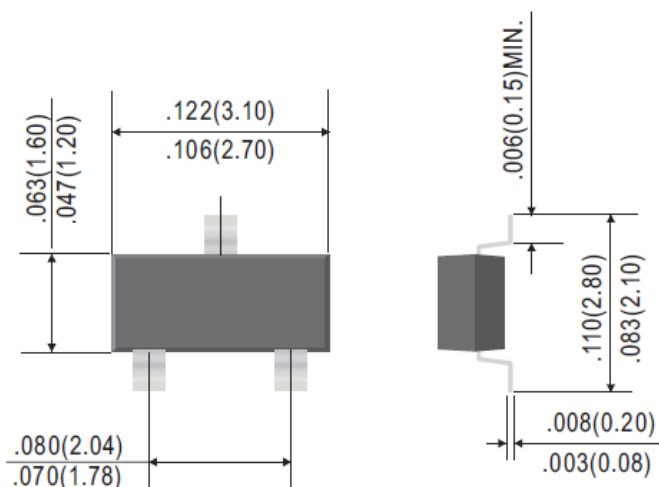


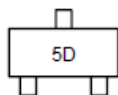
Dimensions in inches and (millimeters)

FEATURES

- RoHS product for packing code suffix "G"
- Halogen free product for packing code suffix "H"
- Moisture Sensitivity Level 1

MARKING:

MARKING DIAGRAM



5D = Device Code

Maximum Ratings (T _A =25°C unless otherwise specified)			
Rating	Symbol	Value	Unit
Reverse Voltage	V _R	100	Vdc
Forward Current	I _F	200	mAdc
Peak Forward Surge Current	I _{FM(surge)}	500	mAdc

Thermal Characteristics ($T_A=25^{\circ}\text{C}$ unless otherwise specified)			
Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board (Note 1.) $T_A = 25^{\circ}\text{C}$ Derate above 25°C	P_D	225	mW
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	1.8	$\text{mW}/^{\circ}\text{C}$
Total Device Dissipation Alumina Substrate (Note 2.) $T_A = 25^{\circ}\text{C}$ Derate above 25°C	P_D	300	mW
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	2.4	$\text{mW}/^{\circ}\text{C}$
Operating/ Junction and Storage Temperature Range	T_J, T_{STG}	417	$^{\circ}\text{C}/\text{W}$
		-55~+150	$^{\circ}\text{C}$

Electrical Characteristics ($T_A=25^{\circ}\text{C}$ unless otherwise specified)				
Characteristic	Symbol	Min.	Max.	Unit
OFF Characteristics				
Reverse Breakdown Voltage ($I_R = 100 \mu\text{Adc}$)	$V_{(BR)}$	100	—	Vdc
Reverse Voltage Leakage Current ($V_R = 20 \text{ Vdc}$) ($V_R = 75 \text{ Vdc}$)	I_R	—	25 5	nAdc μAdc
Diode Capacitance ($V_R = 0, f = 1.0 \text{ MHz}$)	C_T	—	4	pF
Forward Voltage ($I_F = 10 \text{ mAdc}$)	V_F	—	1	Vdc
Reverse Recovery Time ($I_F = I_R = 10 \text{ mAdc}$) (Figure 1)	t_{rr}	—	4	ns

1. FR-5 = 1.0 x 0.75 x 0.062 in.

2. Alumina = 0.4 x 0.3 x 0.024 in. 99.5% alumina.

High-Speed Switching Diode SOT-23

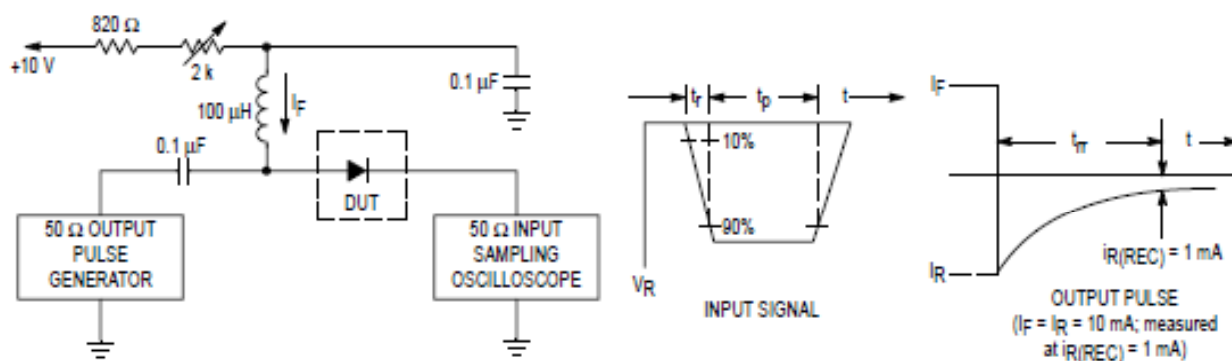


Figure 1. Recovery Time Equivalent Test Circuit

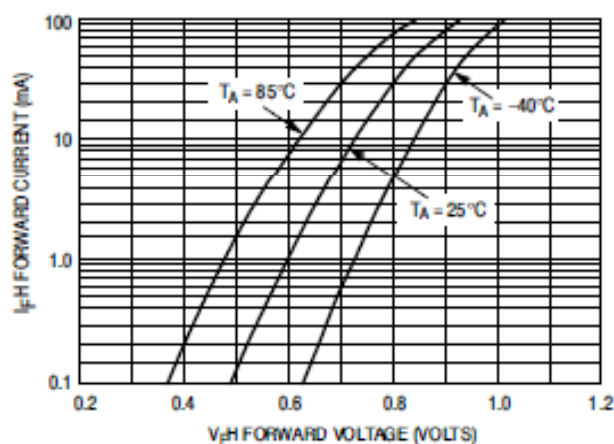


Figure 2. Forward Voltage

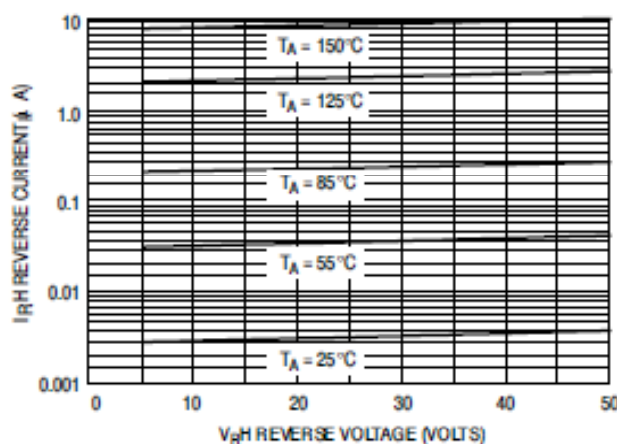


Figure 3. Leakage Current

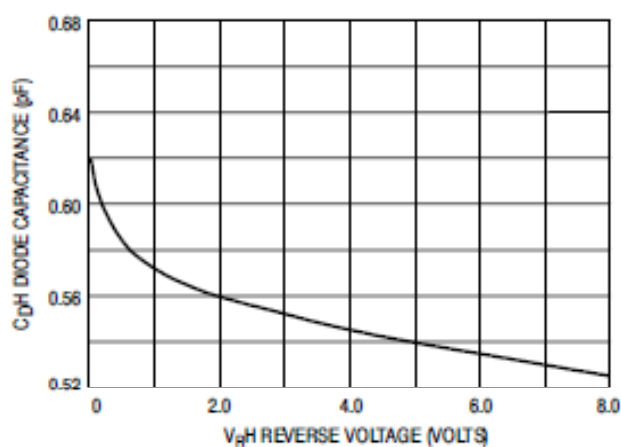


Figure 4. Capacitance